

Voltage Variable Absorptive Attenuator 12 dB, DC - 2.0 GHz

Rev. V5

Features

- Attenuation: 12 dB at 1 GHz Low Intermodulation Products
- Low DC Power Consumption: 50 μW Single Voltage Control: 0 to -4 Volts
- Nanosecond Switching Speed
- Temperature Range: -40°C to +85°C
- SOT-143 Plastic Package
- Tape and Reel Packaging Available

Description

M/A-COM's AT-259 is a GaAs MMIC voltage variable absorptive attenuator in a low cost SOT-143 4-Lead surface mount plastic package. The AT-259 is ideally suited for use where attenuation fine tuning, fast switching and very low power consumption are required.

Typical applications include radio, cellular, GPS equipment and other automatic gain/level control circuits.

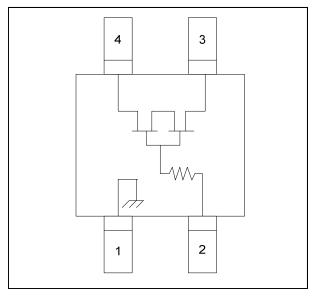
The AT-259 is fabricated with a monolithic GaAs MMIC using a mature 1 micron process. The process features full chip passivation for increased performance and reliability.

Ordering Information ^{1,2}

Part Number	Package		
AT-259	Bulk Packaging		
AT-259TR	Forward Tape and Reel		
AT-259SMB	Sample Board		

- 1. Reference Application Note M513 for reel size information.
- 2. All sample boards include 5 loose parts.

Functional Schematic



Pin Configuration

Pin No.	Function	Pin No.	Function
1	Ground	3	RF2
2	V _C	4	RF1

Absolute Maximum Ratings ³

Parameter	Absolute Maximum
Input Power	+21 dBm
Control Voltage	+5V, -8.5V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

3. Exceeding any one or combination of these limits may cause permanent damage to this device.

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 $^{^{\}dagger}$ Reference Application Note M538 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements.



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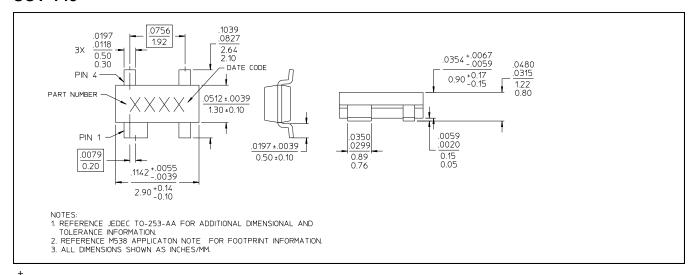
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Electrical Specifications: $T_A = 25$ °C, $Z_0 = 50 \Omega$

Parameter	Test Conditions ⁴	Frequency	Units	Min.	Тур.	Max.
Insertion Loss	_	DC - 0.1 GHz DC - 0.5 GHz DC - 1.0 GHz DC - 2.0 GHz	dB dB dB dB		2.9 3.0 3.2 3.4	3.1 3.2 3.5 3.8
Flatness (Peak to Peak)	5 dB Attenuation 10 dB Attenuation 15 dB Attenuation	DC - 2.0 GHz DC - 2.0 GHz DC - 2.0 GHz	dB dB dB		± 0.2 ± 2.3 ± 7.0	± 0.4 ± 2.5 ± 7.5
Output Impedance	_	_	Ohms	_	50	_
VSWR	_	_	Ratio	1	2.1:1	_
Trise, Tfall	10% to 90% RF, 90% to 10% RF	_	nS	_	3	_
Ton, Toff	50% Control to 90% RF, 50% Control to 10% RF	_	nS		5	_
Transients	In Band	_	mV		10	
Power Handling	Linear Operation Absolute maximum Input Power	_	dBm dBm	_	_	13 21
IP ₂	Measured Relative to Input Power (For two-tone Input Power Up to +5 dBm)	0.05 GHz 0.5 - 2.0 GHz	dBm dBm		34 47	
IP ₃	Measured Relative to Input Power (For two-tone Input Power Up to +5 dBm)	0.05 GHz 0.5 - 2.0 GHz	dBm dBm	18 18.5	31 ⁵ 36 ⁵	

^{4.} Control voltage: 0 to -4 volts @ 20 µA typical.

SOT-143[†]



 $^{^{\}dagger}$ Meets JEDEC moisture sensitivity level 1 requirements.

and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

^{5.} For levels above 6 dB attenuation. For levels below 6 dB, the minimum specification numbers apply.

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results,

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Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298 Visit www.macomtech.com for additional data sheets and product information.

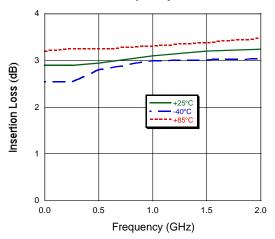


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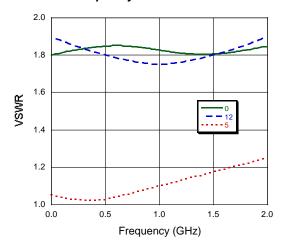
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Typical Performance Curves

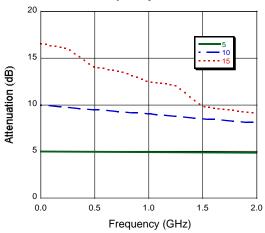
Insertion Loss vs. Frequency



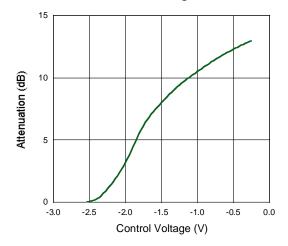
VSWR vs. Frequency



Attenuation vs. Frequency



Attenuation vs. Control Voltage, F = 950 MHz



Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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